

700V N-Channel MOSFET

Description

The MSD2N70 is a N-channel enhancement-mode MOSFET, providing the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost effectiveness. The TO-252 package is universally preferred for all commercial-industrial applications

Features

- 100% EAS Test
- · Rugged Gate Oxide Technology
- Extremely Low Intrinsic Capacitances
- · Remarkable Switching Characteristics
- Unequalled Gate Charge: 10.5 nC (Typ.)
- · Extended Safe Operating Area
- Lower RDS(ON): 5.5 Ω (Typ.) @VGS=10V
- · RoHS compliant package

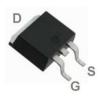
Application

- Adapter
- · Switching Mode Power Supply

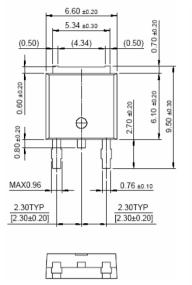
Packing & Order Information

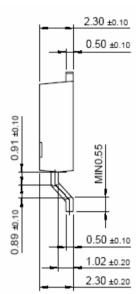
Part No./ R: 2,500/Reel

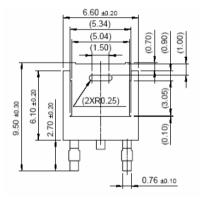
Part No./ T: 80/Tube, 4,000/Box



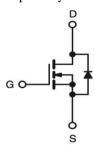








Graphic symbol



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)						
Symbol	Parameter	Value	Unit			
V_{DS}	Drain-Source Voltage	700	V			
V_{GS}	Gate-Source Voltage	±30	V			
I_D	Continuous Drain Current @ TC=25°C	1.6	A			
	Continuous Drain Current @ TC=70°C	1.0	A			
I_{DM}	Pulsed Drain Current	6	A			



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Absolute Maximum Ratings (Tc=25°C unless otherwise noted)					
Symbol	Parameter	Value	Unit		
EAS	Single Pulsed Avalanche Energy	110	mJ		
EAR	Repetitive Avalanche Energy	4.4	mJ		
I _{AR}	Continuous Source Current (Diode Conduction) ^a	1.6	A		
dV/dt	Peak Diode Recovery dV/dt	5.5	V/ns		
P_D	Power Dissipation (TC=25°C)	44	W		
	Power Dissipation (TC=100°C)	0.22	W		
T _J /T _{STG}	Operating Junction and Storage Temperature	-55 to +150	°C		

NOTE:

1. Repetitive rating; pulse width limited by maximum junction temperature.

Thermal Characteristics (Tc=25°C unless otherwise noted)						
Symbol	Parameter	Maximum	Units			
Rthjc	Typical thermal resistance	2.87	°C/W			
$R_{\theta JA}$	Typical thermal resistance	55	C/W			

^{*}When mounted on the minimum pad size recommended (PCB Mount)

Static Characte	ristics				
Symbol	Test Conditions	Min	Тур.	Max.	Units
V_{GS}	$V_{DS}=V_{GS},I_D=250\mu A$	2.0		4.0	V
*R _{DS(ON)}	$V_{GS} = 10V$, $I_D = 0.8$ A		5.5	6.0	Ω
BV _{DSS}	$V_{GS} = 0 \ V$, $I_D = 250 \ \mu A$	700			V
$\Delta BV_{DSS}/\Delta T_{J}$	I_D = 250 μ A, Referenced to 25 $^{\circ}$ C		0.7		
T	$V_{DS} = 700 \text{ V}, V_{GS} = 0 \text{ V}$			10	uA
I _{DS S}	$V_{DS} = 560 \text{ V}, V_{GS} = 0 \text{ V}, T_j = 125 ^{\circ}\text{C}$			100	
I_{GSSF}	$V_{DS} = 30 \text{ V}, V_{Ds} = 0 \text{ V}$			100	nA
I _{GSSR}	$V_{DS} = -30 \text{ V}, V_{Ds} = 0 \text{ V}$			-100	nA

Dynamic Characteristics					
Symbol	Test Conditions	Min	Тур.	Max.	Units
C_{ISS}			340	445	pF
Coss	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ $F = 1.0 \text{MHz}$		45	60	pF
Crss	$\Gamma = 1.0 \text{Winz}$		7.5	10	pF
t _{d(on)}			10	20	ns
$t_{\rm r}$	$V_{DS} = 350 \text{ V}, I_D = 1.6 \text{ A},$		25	50	ns
t _{d(off)}	$R_G = 25 \Omega$		20	40	ns
tf			25	50	ns



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Dynamic Characteristics						
Symbol	Test Conditions	Min	Typ.	Max.	Units	
$Q_{\rm g}$			10.5	14	nC	
Q_{gs}	$V_{DS} = 560 \text{ V}, I_D = 1.6 \text{ A},$ $V_{GS} = 10 \text{ V}$		2.0			
Q_{gd}	$V_{GS} = 10^{\circ} V$		4.0			

Source-Drain Diode Characteristics					
Symbol	Test Conditions	Min	Typ.	Max.	Units
I_S				1.6	
I _{SM}				6	A
V _{SD}	$IF = 1.6 A, V_{GS} = 0 V$			1.5	V
t _{rr}	TE 1 6 A VI O VI UE/U 100A/W		250		ns
Q _{rr}	$ Arr$ IF = 1.6 A , V_{GS} = 0 V , dIF/dt=100A/ μ s		1.2		uC

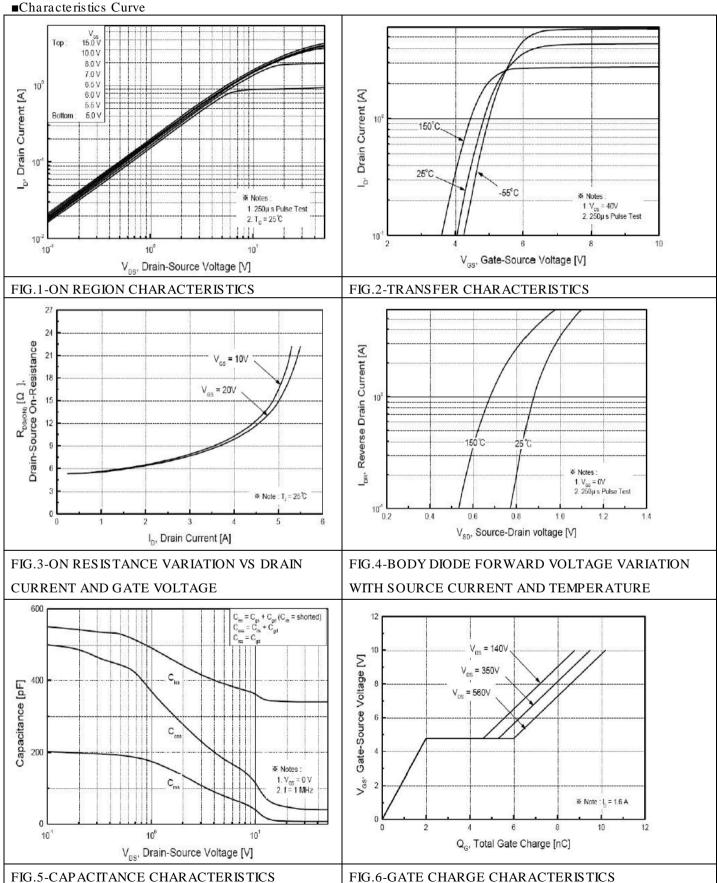
NOTE:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. I_{AS} =1.6A, V_{DD} =50V, R_G =25W, Starting TJ =25°C
- 3. I_{SD} ≤1.6A, di/dt≤300A/ μ s, VDD≤BVDSS , Starting TJ =25 °C
- 4. Pulse Test : Pulse Width ≤ 300µs, Duty Cycle ≤ 2%
- 5. Essentially Independent of Operating Temperature



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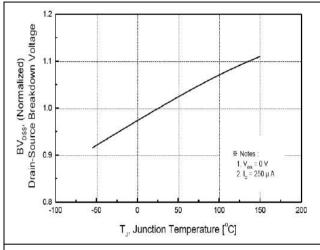






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■Characteristics Curve



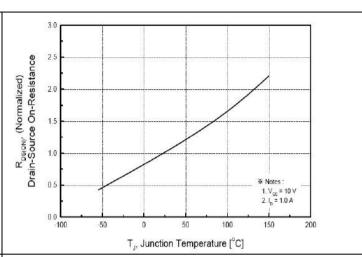


FIG.7-BREAKDOWN VOLTAGE VARIATION VS TEMPERATURE

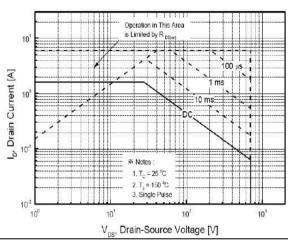


FIG.8-ON-RESISTANCE VARIATION VS TEMPERATURE

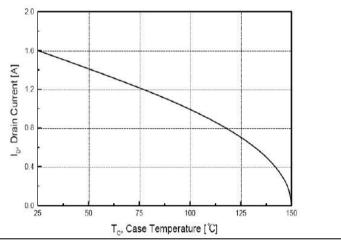


FIG.9-MAXIMUM SAFE OPERATING AREA

 $\label{eq:fig.10-maximum} \textbf{FIG.10-MAXIMUM DRAIN CURRENT VS CASE} \\ \textbf{TEMPERATURE}$

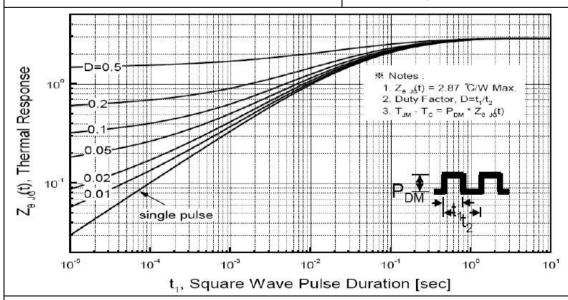


FIG.11-TRANSIENT THERMAL RESPONSE CURVE



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■Characteristics Test Circuit & Waveform

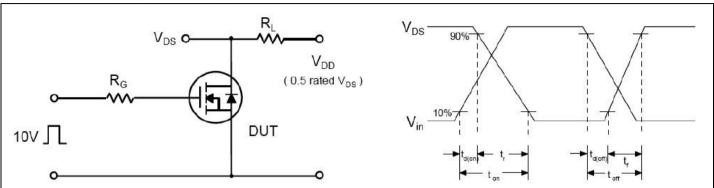


Fig 12. Resistive Switching Test Circuit & Waveforms

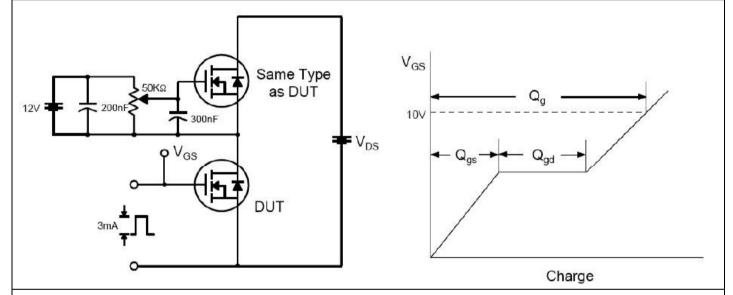
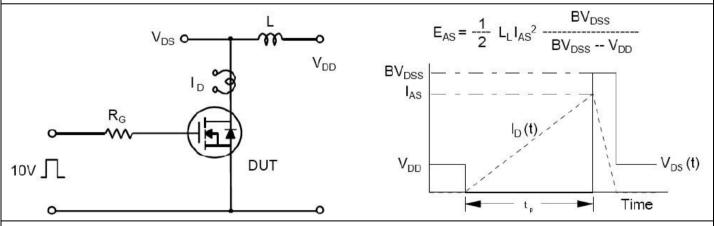


Fig 13. Gate Charge Test Circuit & Waveform





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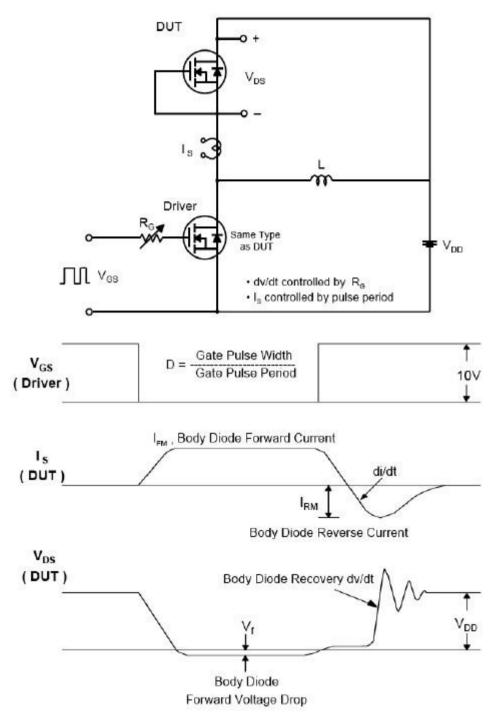


Fig 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



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